

Preliminary

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT4S03AU

VHF~UHF Band Low Noise Amplifier Applications

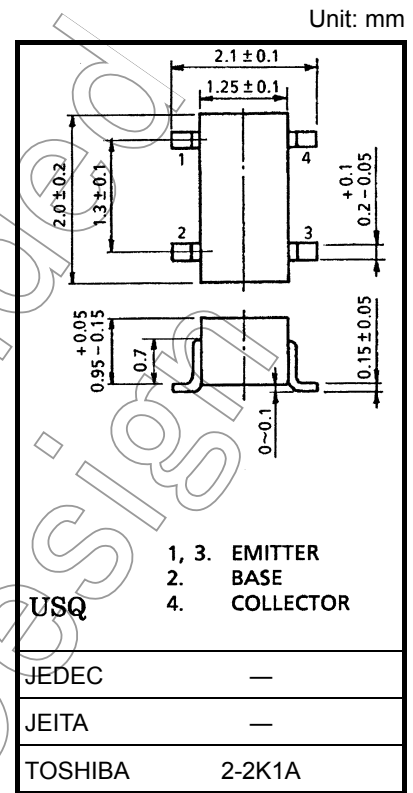
- Low noise figure: NF = 1.4dB (f = 2 GHz)
- High gain: gain = 9dB (f = 2 GHz)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	10	V
Collector-emitter voltage	V _{CEO}	5	V
Emitter-base voltage	V _{EBO}	2	V
Base current	I _C	40	mA
Collector current	I _B	10	mA
Collector power dissipation	P _C	100	mW
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-55~125	°C

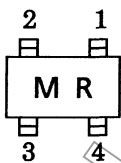
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.006 g (typ.)

Marking



Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition frequency	f _T (1)	V _{CE} = 1 V, I _C = 5 mA	2	4.5	—	GHz
	f _T (2)	V _{CE} = 3 V, I _C = 10 mA	7	10	—	
Insertion gain	S _{21e} ² (1)	V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	3.5	5.5	—	dB
	S _{21e} ² (2)	V _{CE} = 3 V, I _C = 20 mA, f = 2 GHz	7	9	—	
Noise figure	NF (1)	V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	—	1.7	3	dB
	NF (2)	V _{CE} = 3 V, I _C = 7 mA, f = 2 GHz	—	1.4	2.2	

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 5\text{ V}, I_E = 0$	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 1\text{ V}, I_C = 0$	—	—	1	μA
DC current gain	h_{FE}	$V_{CE} = 1\text{ V}, I_C = 5\text{ mA}$	80	—	160	
Reverse transfer capacitance	C_{re}	$V_{CB} = 1\text{ V}, I_E = 0, f = 1\text{ MHz}$ (Note)	—	0.7	1.05	pF

Note: C_{re} is measured by 3 terminal method with capacitance bridge.

Caution

This device is sensitive to electrostatic discharge. Please handle with caution.

Not Recommended
for New Design

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